LM2665 Switched Capacitor Voltage Converter

Check for Samples: LM2665

FEATURES

- **Doubles or Splits Input Supply Voltage**
- **6-Pin SOT-23 Package**
- **12Ω Typical Output Impedance**
- **90% Typical Conversion Efficiency at 40 mA**
- **1µA Typical Shutdown Current**

APPLICATIONS

- **Cellular Phones**
- **Pagers**
- **PDAs**
- **Operational Amplifier Power Suppliers**
- **Interface Power Suppliers**
- **Handheld Instruments**

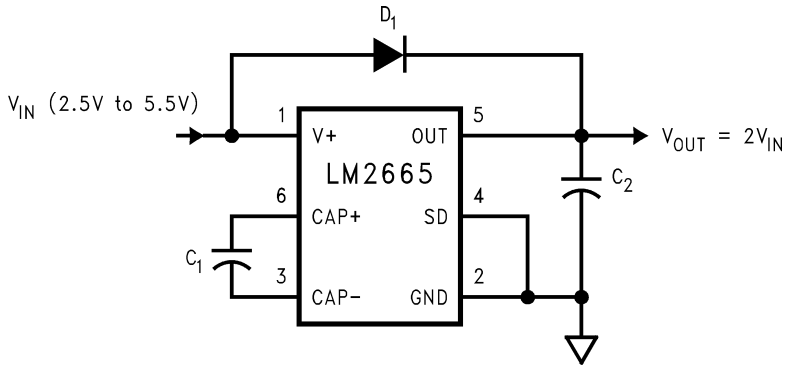
DESCRIPTION

The LM2665 CMOS charge-pump voltage converter operates as a voltage doubler for an input voltage in the range of +2.5V to +5.5V. Two low cost capacitors and a diode (needed during start-up) are used in this circuit to provide up to 40 mA of output current. The LM2665 can also work as a voltage divider to split a voltage in the range of +1.8V to +11V in half.

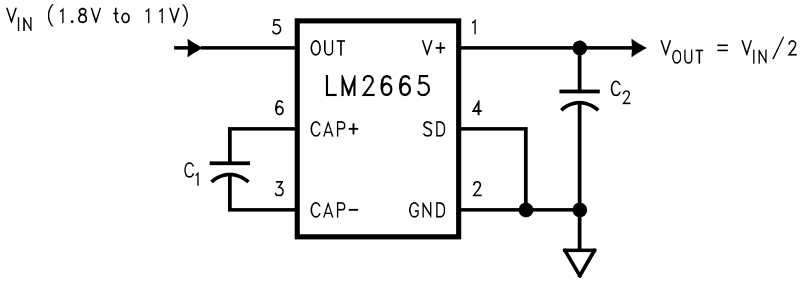
The LM2665 operates at 160 kHz oscillator frequency to reduce output resistance and voltage ripple. With an operating current of only 650 µA (operating efficiency greater than 90% with most loads) and 1µA typical shutdown current, the LM2665 provides ideal performance for battery powered systems. The device is in a SOT-23 package.

Basic Application Circuits

Voltage Doubler



Splitting V_{in} in Half



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings(1)(2)

V+ to GND Voltage:	5.8V
OUT to GND Voltage:	11.6V
OUT to V+ Voltage:	5.8V
SD	(GND − 0.3V) to (V+ + 0.3V)
V+ and OUT Continuous Output Current	50 mA
Output Short-Circuit Duration to GND(3)	1 sec.
Continuous Power Dissipation (T_A = 25°C)(4)	600 mW
T_{JMax}(4)	150°C
θ_{JA}(4)	210°C/W
Operating Junction Temperature Range	−40° to 85°C
Storage Temperature Range	−65°C to +150°C
Lead Temp. (Soldering, 10 seconds)	300°C
ESD Rating	2kV

(1) Absolute maximum ratings indicate limits beyond which damage to the device may occur. Electrical specifications do not apply when operating the device beyond its rated operating conditions.
(2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
(3) OUT may be shorted to GND for one second without damage. However, shorting OUT to V+ may damage the device and should be avoided. Also, for temperatures above 85°C, OUT must not be shorted to GND or V+, or device may be damaged.
(4) The maximum allowable power dissipation is calculated by using $P_{DMax} = (T_{JMax} - T_A)/\theta_{JA}$, where T_{JMax} is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction-to-ambient thermal resistance of the specified package.

Electrical Characteristics

Limits in standard typeface are for T_J = 25°C, and limits in **boldface** type apply over the full operating temperature range. Unless otherwise specified: V+ = 5V, $C_1 = C_2$ = 3.3 µF.(1)

Symbol	Parameter	Condition	Min (2)	Typ (3)	Max (2)	Units
V+	Supply Voltage		**2.5**		**5.5**	V
I_Q	Supply Current	No Load		650	**1250**	µA
I_{SD}	Shutdown Supply Current			1		µA
V_{SD}	Shutdown Pin Input Voltage	Shutdown Mode	**2.0** (4)			V
		Normal Operation			**0.8** (5)	
I_L	Output Current		**40**			mA
R_{SW}	Sum of the $R_{ds(on)}$ of the four internal MOSFET switches	I_L = 40 mA		3.5	**8**	Ω
R_{OUT}	Output Resistance(6)	I_L = 40 mA		12	**25**	Ω
f_{OSC}	Oscillator Frequency		**(7)80**	160		kHz
f_{SW}	Switching Frequency	(7)	**40**	80		kHz
P_{EFF}	Power Efficiency	R_L (1.0k) between GND and OUT	**86**	93		%
		I_L = 40 mA to GND		90		

(1) In the test circuit, capacitors C_1 and C_2 are 3.3 µF, 0.3Ω maximum ESR capacitors. Capacitors with higher ESR will increase output resistance, reduce output voltage and efficiency.
(2) Min. and Max. limits are guaranteed by design, test, or statistical analysis.
(3) Typical numbers are not guaranteed but represent the most likely norm.
(4) The minimum input high for the shutdown pin equals 40% of V+.
(5) The maximum input low of the shutdown pin equals 20% of V+.
(6) Specified output resistance includes internal switch resistance and capacitor ESR. See the details in the application information for positive voltage doubler.
(7) The output switches operate at one half of the oscillator frequency, $f_{OSC} = 2f_{SW}$.

Electrical Characteristics (continued)

Limits in standard typeface are for T_J = 25°C, and limits in **boldface** type apply over the full operating temperature range. Unless otherwise specified: V+ = 5V, $C_1 = C_2$ = 3.3 µF.(1)

Symbol	Parameter	Condition	Min (2)	Typ (3)	Max (2)	Units
V_{OEFF}	Voltage Conversion Efficiency	No Load	**99**	99.96		%

Test Circuit

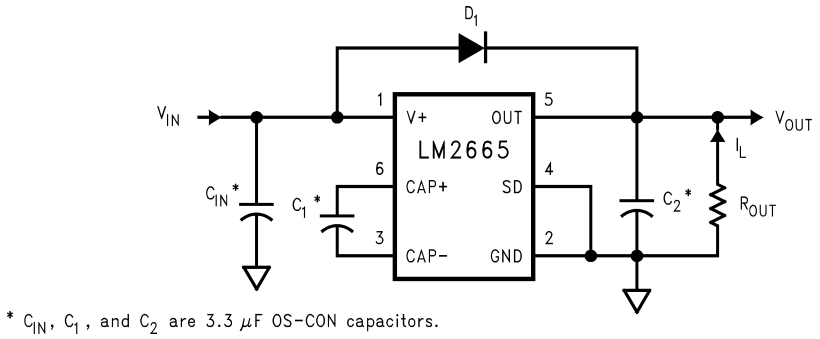


Figure 1. LM2665 Test Circuit

Typical Performance Characteristics

(Circuit of Figure 1, V+ = 5V unless otherwise specified)

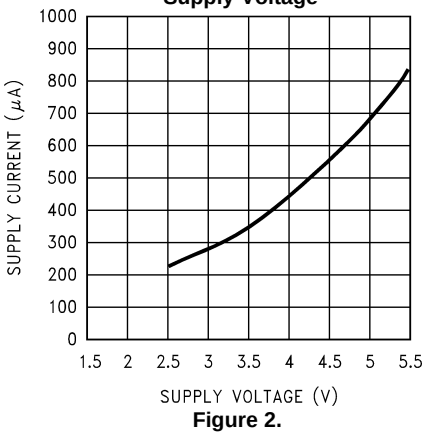


Figure 2.

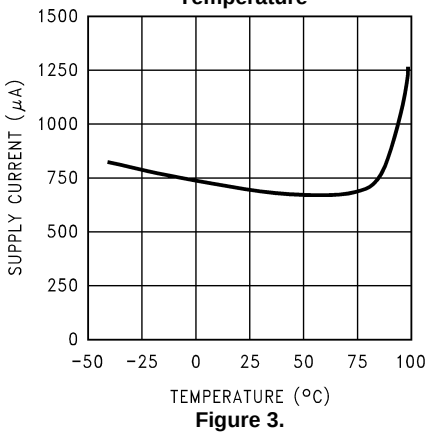


Figure 3.

Typical Performance Characteristics (continued)

(Circuit of Figure 1, V+ = 5V unless otherwise specified)

Output Source Resistance vs Supply Voltage

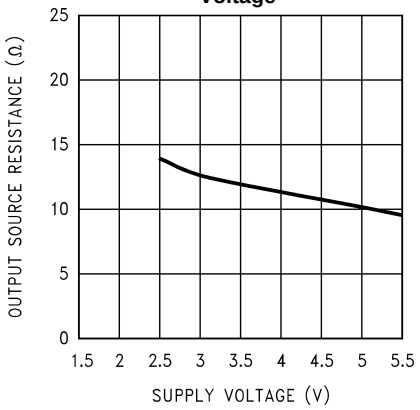


Figure 4.

Output Source Resistance vs Temperature

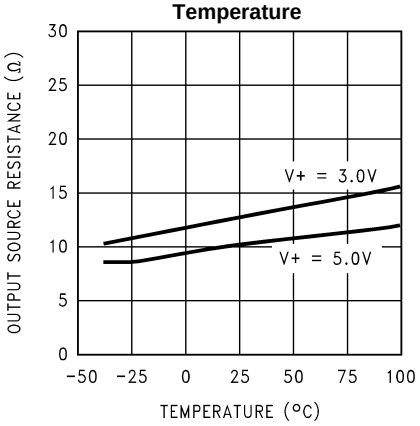


Figure 5.

Output Voltage Drop vs Load Current

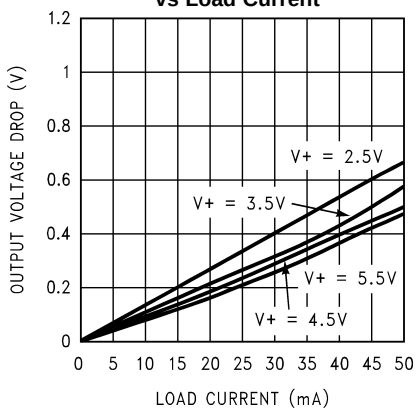


Figure 6.

Efficiency vs Load Current

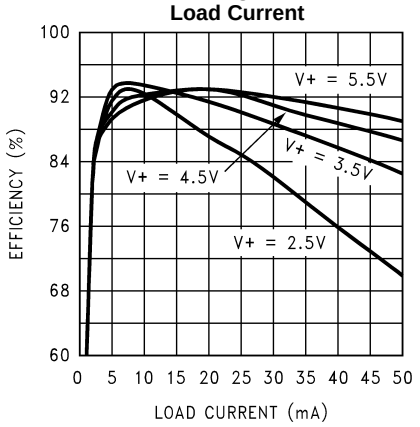


Figure 7.

Oscillator Frequency vs Supply Voltage

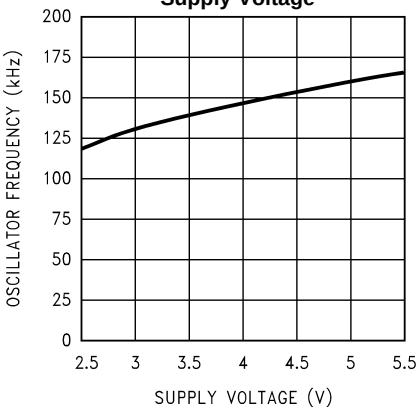


Figure 8.

Oscillator Frequency vs Temperature

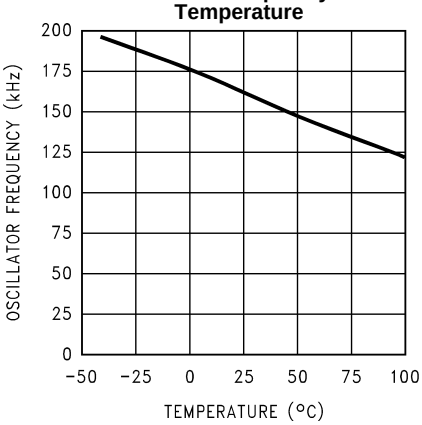


Figure 9.

Typical Performance Characteristics (continued)

(Circuit of Figure 1, V+ = 5V unless otherwise specified)

Shutdown Supply Current vs Temperature

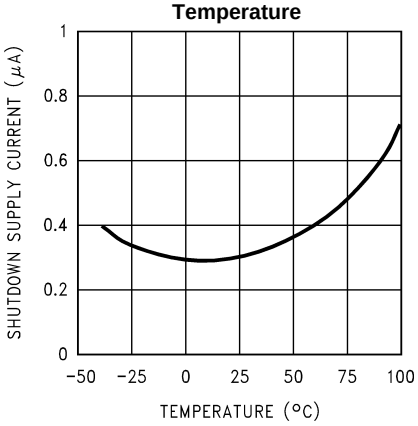


Figure 10.

CONNECTION DIAGRAM

6-Pin Small Outline Package

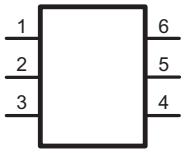


Figure 11. DBV Package Top View

Figure 12. Actual Size

Pin Functions

Pin	Name	Function	
		Voltage Doubler	Voltage Split
1	V+	Power supply positive voltage input.	Positive voltage output.
2	GND	Power supply ground input	Same as doubler
3	CAP−	Connect this pin to the negative terminal of the charge-pump capacitor	Same as doubler.
4	SD	Shutdown control pin, tie this pin to ground in normal operation.	Same as doubler.
5	OUT	Positive voltage output.	Power supply positive voltage input
6	CAP+	Connect this pin to the positive terminal of the charge-pump capacitor.	Same as doubler

Circuit Description

The LM2665 contains four large CMOS switches which are switched in a sequence to double the input supply voltage. Energy transfer and storage are provided by external capacitors. Figure 13 illustrates the voltage conversion scheme. When S_2 and S_4 are closed, C_1 charges to the supply voltage V+. During this time interval, switches S_1 and S_3 are open. In the next time interval, S_2 and S_4 are open; at the same time, S_1 and S_3 are closed, the sum of the input voltage V+ and the voltage across C_1 gives the 2V+ output voltage when there is no load. The output voltage drop when a load is added is determined by the parasitic resistance ($R_{ds(on)}$ of the MOSFET switches and the ESR of the capacitors) and the charge transfer loss between capacitors. Details will be discussed in the following application information section.

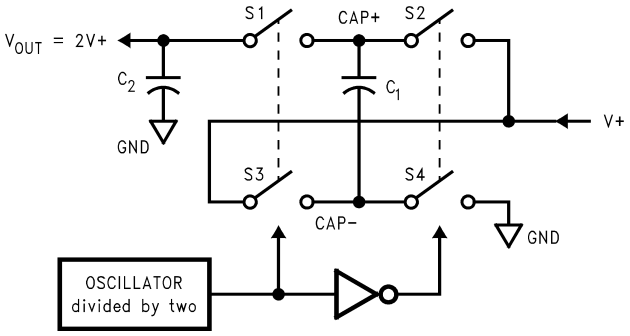


Figure 13. Voltage Doubling Principle

APPLICATION INFORMATION

POSITIVE VOLTAGE DOUBLER

The main application of the LM2665 is to double the input voltage. The range of the input supply voltage is 2.5V to 5.5V.

The output characteristics of this circuit can be approximated by an ideal voltage source in series with a resistance. The voltage source equals 2V+. The output resistance R_{out} is a function of the ON resistance of the internal MOSFET switches, the oscillator frequency, the capacitance and ESR of C_1 and C_2. Since the switching current charging and discharging C_1 is approximately twice as the output current, the effect of the ESR of the pumping capacitor C_1 will be multiplied by four in the output resistance. The output capacitor C_2 is charging and discharging at a current approximately equal to the output current, therefore, its ESR only counts once in the output resistance. A good approximation of R_{out} is:

$$R_{OUT} \cong 2R_{SW} + \frac{2}{f_{OSC} \times C_1} + 4ESR_{C1} + ESR_{C2} \quad (1)$$

where R_{SW} is the sum of the ON resistance of the internal MOSFET switches shown in Figure 13.

The peak-to-peak output voltage ripple is determined by the oscillator frequency, the capacitance and ESR of the output capacitor C_2:

$$V_{RIPPLE} = \frac{I_L}{f_{OSC} \times C_2} + 2 \times I_L \times ESR_{C2} \quad (2)$$

High capacitance, low ESR capacitors can reduce both the output resistance and the voltage ripple.

The Schottky diode D_1 is only needed for start-up. The internal oscillator circuit uses the OUT pin and the GND pin. Voltage across OUT and GND must be larger than 1.8V to insure the operation of the oscillator. During start-up, D_1 is used to charge up the voltage at the OUT pin to start the oscillator; also, it protects the device from turning-on its own parasitic diode and potentially latching-up. Therefore, the Schottky diode D_1 should have enough current carrying capability to charge the output capacitor at start-up, as well as a low forward voltage to prevent the internal parasitic diode from turning-on. A Schottky diode like 1N5817 can be used for most applications. If the input voltage ramp is less than 10V/ms, a smaller Schottky diode like MBR0520LT1 can be used to reduce the circuit size.

SPLIT V+ IN HALF

Another interesting application shown in the Basic Application Circuits is using the LM2665 as a precision voltage divider. . This circuit can be derived from the voltage doubler by switching the input and output connections. In the voltage divider, the input voltage applies across the OUT pin and the GND pin (which are the power rails for the internal oscillator), therefore no start-up diode is needed. Also, since the off-voltage across each switch equals $V_{in}/2$, the input voltage can be raised to +11V.

SHUTDOWN MODE

A shutdown (SD) pin is available to disable the device and reduce the quiescent current to 1 µA. In normal operating mode, the SD pin is connected to ground. The device can be brought into the shutdown mode by applying to the SD pin a voltage greater than 40% of the V+ pin voltage.

CAPACITOR SELECTION

As discussed in the *Positive Voltage Doubler* section, the output resistance and ripple voltage are dependent on the capacitance and ESR values of the external capacitors. The output voltage drop is the load current times the output resistance, and the power efficiency is

$$\eta = \frac{P_{OUT}}{P_{IN}} = \frac{I_L{}^2 R_L}{I_L{}^2 R_L + I_L{}^2 R_{OUT} + I_Q (V+)} \quad (3)$$

Where $I_Q(V+)$ is the quiescent power loss of the IC device, and $I_L{}^2R_{out}$ is the conversion loss associated with the switch on-resistance, the two external capacitors and their ESRs.

The selection of capacitors is based on the specifications of the dropout voltage (which equals I_{out} R_{out}), the output voltage ripple, and the converter efficiency. Low ESR capacitors () are recommended to maximize efficiency, reduce the output voltage drop and voltage ripple.

Low ESR Capacitor Manufacturers

Manufacturer	Phone	Capacitor Type
Nichicon Corp.	(708)-843-7500	PL & PF series, through-hole aluminum electrolytic
AVX Corp.	(803)-448-9411	TPS series, surface-mount tantalum
Sprague	(207)-324-4140	593D, 594D, 595D series, surface-mount tantalum
Sanyo	(619)-661-6835	OS-CON series, through-hole aluminum electrolytic
Murata	(800)-831-9172	Ceramic chip capacitors
Taiyo Yuden	(800)-348-2496	Ceramic chip capacitors
Tokin	(408)-432-8020	Ceramic chip capacitors

Other Applications

PARALLELING DEVICES

Any number of LM2665s can be paralleled to reduce the output resistance. Each device must have its own pumping capacitor C_1, while only one output capacitor C_{out} is needed as shown in Figure 14. The composite output resistance is:

$$R_{OUT} = \frac{R_{OUT} \text{ of each LM2665}}{\text{Number of Devices}} \quad (4)$$

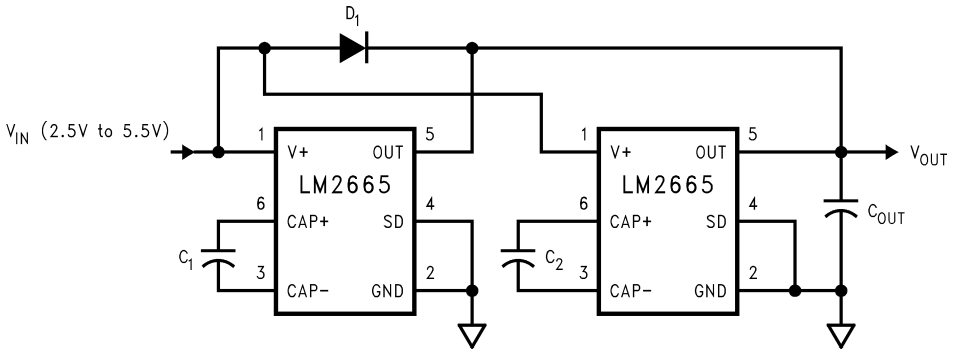


Figure 14. Lowering Output Resistance by Paralleling Devices

CASCADING DEVICES

Cascading the LM2665s is an easy way to produce a greater voltage (A two-stage cascade circuit is shown in Figure 15).

The effective output resistance is equal to the weighted sum of each individual device:

$$R_{out} = 1.5R_{out\_1} + R_{out\_2} \quad (5)$$

Note that, the increasing of the number of cascading stages is practically limited since it significantly reduces the efficiency, increases the output resistance and output voltage ripple.

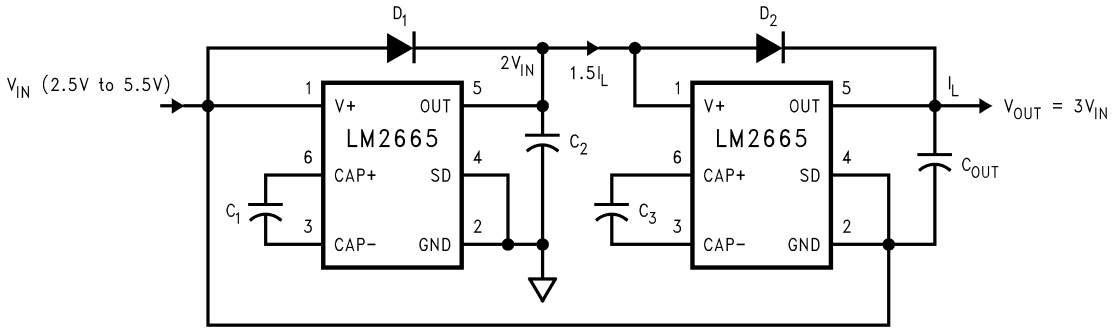


Figure 15. Increasing Output Voltage by Cascading Devices

REGULATING V_{OUT}

It is possible to regulate the output of the LM2665 by use of a low dropout regulator (such as LP2980-5.0). The whole converter is depicted in Figure 16.

A different output voltage is possible by use of LP2980-3.3, LP2980-3.0, or LP2980-adj.

Note that, the following conditions must be satisfied simultaneously for worst case design:

$$2V_{in\_min} > V_{out\_min} + V_{drop\_max}\ (LP2980) + I_{out\_max} \times R_{out\_max}\ (LM2665) \quad (6)$$

$$2V_{in\_max} < V_{out\_max} + V_{drop\_min}\ (LP2980) + I_{out\_min} \times R_{out\_min}\ (LM2665) \quad (7)$$

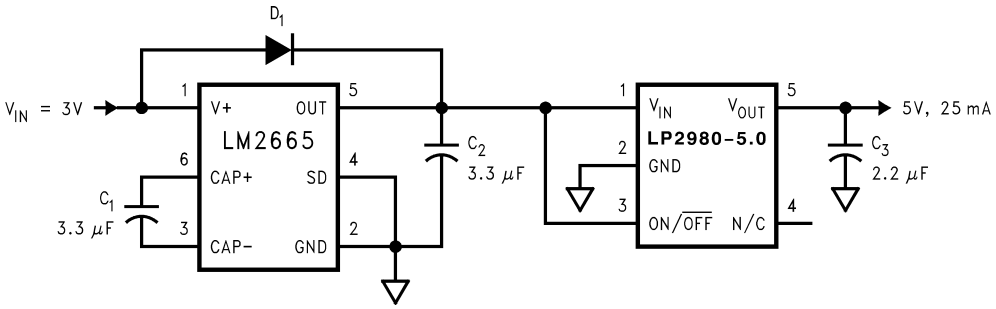


Figure 16. Generate a Regulated +5V from +3V Input Voltage

REVISION HISTORY

Changes from Revision E (May 2013) to Revision F **Page**

- Changed layout of National Data Sheet to TI format 9

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM2665M6	NRND	SOT-23	DBV	6	1000	TBD	Call TI	Call TI	-40 to 85	S04A	
LM2665M6/NOPB	ACTIVE	SOT-23	DBV	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	S04A	Samples
LM2665M6X	NRND	SOT-23	DBV	6	3000	TBD	Call TI	Call TI	-40 to 85	S04A	
LM2665M6X/NOPB	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	S04A	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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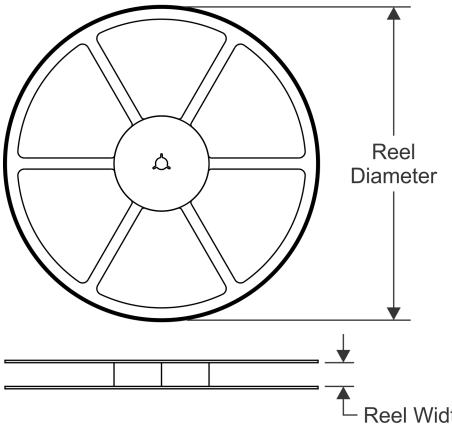
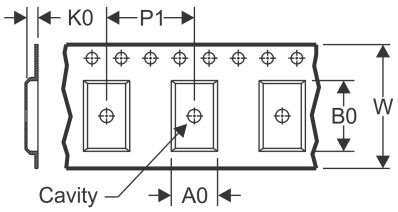
TAPE AND REEL INFORMATION

REEL DIMENSIONS

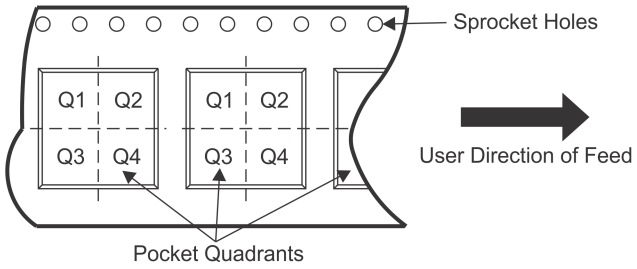


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

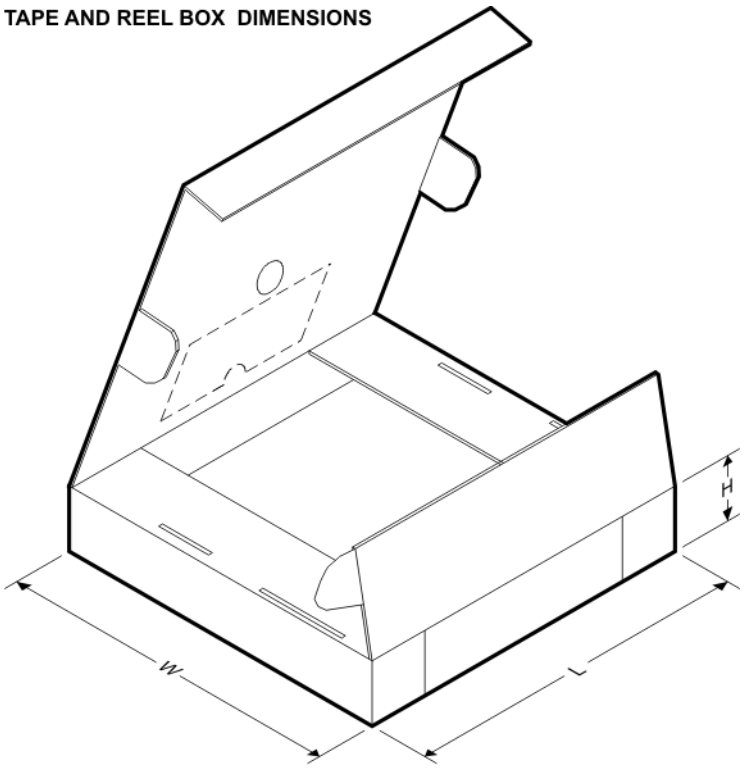
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM2665M6	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM2665M6/NOPB	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM2665M6X	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM2665M6X/NOPB	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

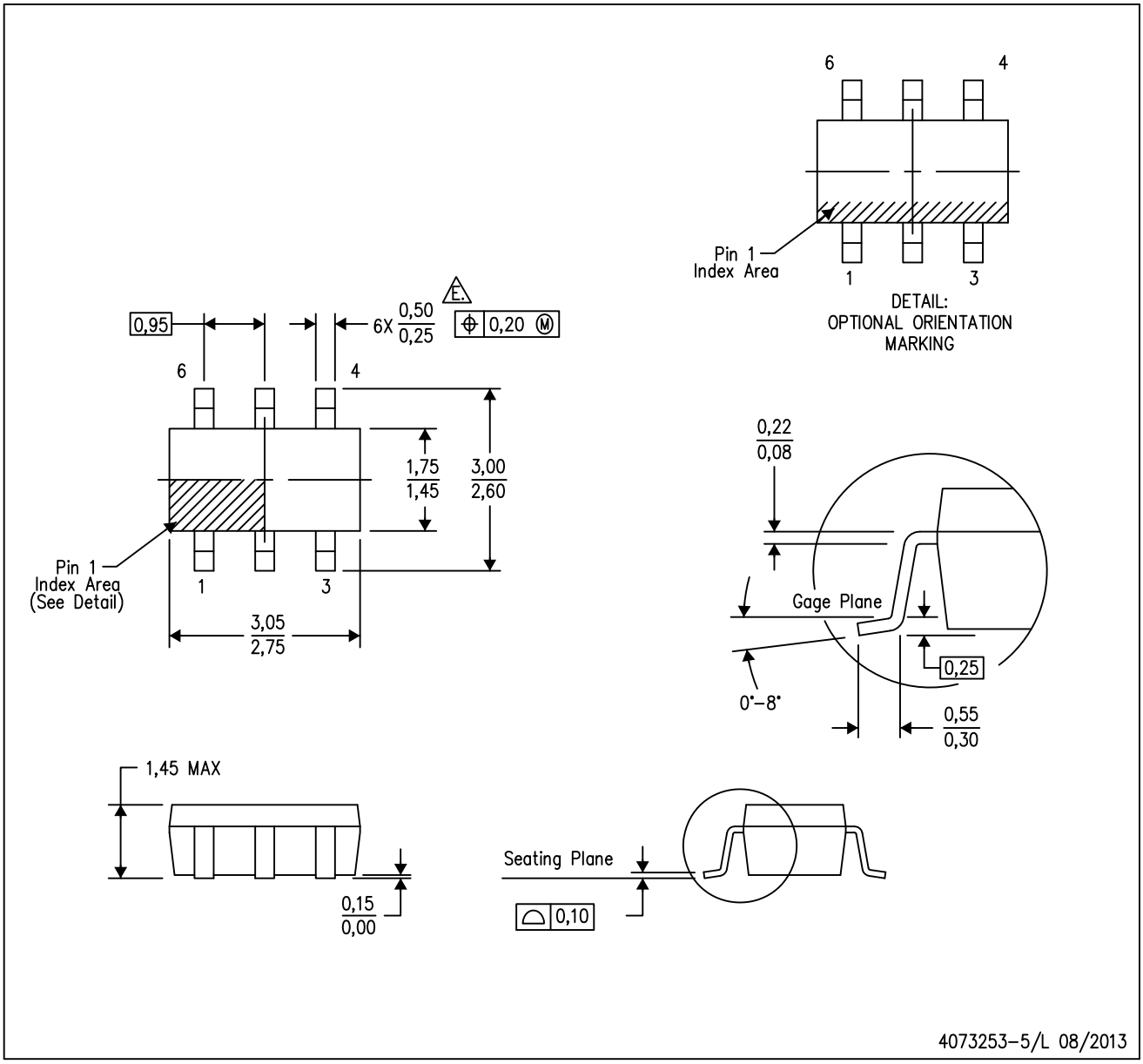
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM2665M6	SOT-23	DBV	6	1000	210.0	185.0	35.0
LM2665M6/NOPB	SOT-23	DBV	6	1000	210.0	185.0	35.0
LM2665M6X	SOT-23	DBV	6	3000	210.0	185.0	35.0
LM2665M6X/NOPB	SOT-23	DBV	6	3000	210.0	185.0	35.0

DBV (R–PDSO–G6) PLASTIC SMALL–OUTLINE PACKAGE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
E. Falls within JEDEC MO–178 Variation AB, except minimum lead width.

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